COMPLIANT

HALOGEN

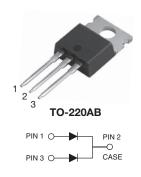
FREE



## Vishay General Semiconductor

# Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5.0 \text{ A}$ 



| PRIMARY CHARACTERISTICS   |                |  |  |  |  |  |  |
|---|----------------|--|--|--|--|--|--|
| I <sub>F(AV)</sub>  | 2 x 20 A       |  |  |  |  |  |  |
| $V_{RRM}$   | 45 V           |  |  |  |  |  |  |
| I <sub>FSM</sub>  | 250 A          |  |  |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 20 A (T <sub>J</sub> = 125 °C) | 0.47 V         |  |  |  |  |  |  |
| T <sub>J</sub> max.   | 175 °C         |  |  |  |  |  |  |
| Package   | TO-220AB       |  |  |  |  |  |  |
| Circuit configuration   | Common cathode |  |  |  |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix

meets JESD 201 class 2 whisker test

Mounting torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                    |            |                               |             |      |  |  |  |  |
|--|------------|-------------------------------|-------------|------|--|--|--|--|
| PARAMETER  |            | SYMBOL                        | VX40M45C    | UNIT |  |  |  |  |
| Maximum repetitive peak reverse voltage  |            | $V_{RRM}$                     | 45          | V    |  |  |  |  |
| Maximum average forward rectified current (fig. 1)                                 | per device |                               | 40          | А    |  |  |  |  |
|  | per diode  | I <sub>F(AV)</sub>            | 20          |      |  |  |  |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load |            | I <sub>FSM</sub>              | 250         | А    |  |  |  |  |
| Operating junction temperature range   |            | T <sub>J</sub> <sup>(1)</sup> | -40 to +175 | ۰.   |  |  |  |  |
| Storage temperature range  |            | T <sub>STG</sub>              | -40 to +175 | °C   |  |  |  |  |

#### Note

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient: dPp/dTJ < 1/ReJA



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted) |                       |                         |                               |      |      |      |  |  |  |
|---|-----------------------|-------------------------|-------------------------------|------|------|------|--|--|--|
| PARAMETER   | TEST CO               | NDITIONS                | SYMBOL                        | TYP. | MAX. | UNIT |  |  |  |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 5 A  |                         | V <sub>F</sub> <sup>(1)</sup> | 0.46 | -    | V    |  |  |  |
|   | I <sub>F</sub> = 10 A | $T_J = 25  ^{\circ}C$   |                               | 0.50 | -    |      |  |  |  |
|   | I <sub>F</sub> = 20 A |                         |                               | 0.55 | 0.60 |      |  |  |  |
|   | I <sub>F</sub> = 5 A  |                         |                               | 0.34 | -    |      |  |  |  |
|   | I <sub>F</sub> = 10 A | T <sub>J</sub> = 125 °C |                               | 0.39 | -    |      |  |  |  |
|   | I <sub>F</sub> = 20 A |                         |                               | 0.47 | 0.53 |      |  |  |  |
| Reverse current at rated V <sub>R</sub> per diode                                 | V <sub>B</sub> = 45 V | T <sub>J</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | -    | 0.25 | mA   |  |  |  |
|   | v <sub>R</sub> = 45 v | T <sub>J</sub> = 125 °C | 'R (=)                        | 4.5  | 20   |      |  |  |  |
| Typical junction capacitance  | 4.0 V, 1 MHz          |                         | CJ                            | 3500 | -    | pF   |  |  |  |

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5 \text{ ms}$ 

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                       |          |      |  |  |
|---|-----------------------|----------|------|--|--|
| PARAMETER   | SYMBOL                | VX40M45C | UNIT |  |  |
| Typical thermal resistance per device                                   | R <sub>0</sub> JC (1) | 1        | °C/W |  |  |

#### Note

(1) Thermal resistance junction-to-case to follow JEDEC® 51-14 transient dual interface test method (TDIM)

| ORDERING INFORMATION (Example) |                 |              |               |               |  |  |  |
|--------------------------------|-----------------|--------------|---------------|---------------|--|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |  |
| VX40M45C-M3/P                  | 2.03            | Р            | 50/tube       | Tube          |  |  |  |
| VX40M45CHM3/P (1)              | 2.03            | Р            | 50/tube       | Tube          |  |  |  |

### Note

(1) AEC-Q101 qualified



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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

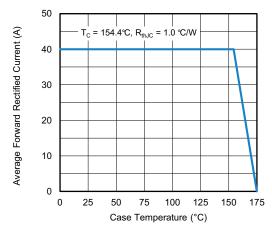


Fig. 1 - Maximum Forward Current Derating Curve

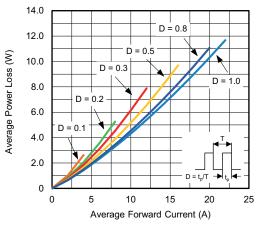


Fig. 2 - Average Power Loss Characteristics

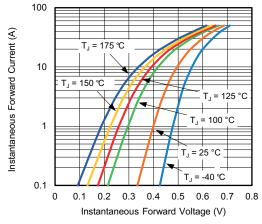


Fig. 3 - Typical Instantaneous Forward Characteristics

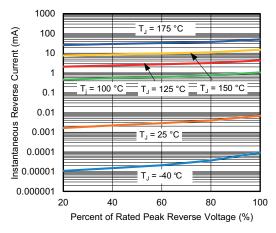


Fig. 4 - Typical Reverse Leakage Characteristics

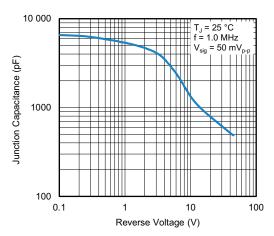


Fig. 5 - Typical Junction Capacitance

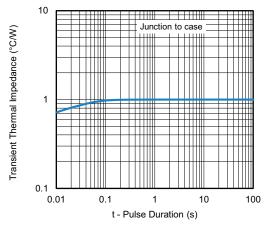
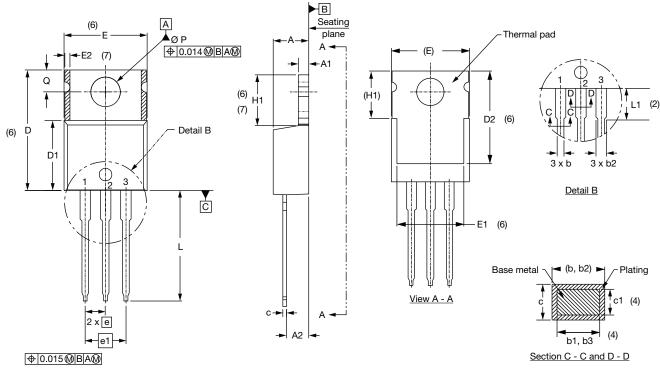


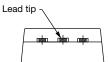
Fig. 6 - Typical Transient Thermal Impedance



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### **DIMENSIONS** in millimeters (inches) **TO-220AB**





#### Conforms to JEDEC® outline TO-220AB

| SYMBOL   | MILLIM | IETERS | INC   | HES   | NOTES |       | SYMBOL   | MILLIMETERS |       | INCHES |       | NOTES |
|----------|--------|--------|-------|-------|-------|-------|----------|-------------|-------|--------|-------|-------|
| STIVIDUL | MIN.   | MAX.   | MIN.  | MAX.  | NOTES | NOTES | STIVIBUL | MIN.        | MAX.  | MIN.   | MAX.  | NOTES |
| Α        | 4.25   | 4.65   | 0.167 | 0.183 |       |       | D2       | 11.68       | 12.88 | 0.460  | 0.507 | 6     |
| A1       | 1.14   | 1.40   | 0.045 | 0.055 |       |       | E        | 10.11       | 10.51 | 0.398  | 0.414 | 3, 6  |
| A2       | 2.56   | 2.92   | 0.101 | 0.115 |       |       | E1       | 6.86        | 8.89  | 0.270  | 0.350 | 6     |
| b        | 0.69   | 1.01   | 0.027 | 0.040 |       |       | E2       | -           | 0.76  | -      | 0.030 | 7     |
| b1       | 0.38   | 0.97   | 0.015 | 0.038 | 4     |       | е        | 2.41        | 2.67  | 0.095  | 0.105 |       |
| b2       | 1.20   | 1.73   | 0.047 | 0.068 |       |       | e1       | 4.88        | 5.28  | 0.192  | 0.208 |       |
| b3       | 1.14   | 1.73   | 0.045 | 0.068 | 4     |       | H1       | 5.84        | 6.86  | 0.230  | 0.270 | 6, 7  |
| С        | 0.36   | 0.61   | 0.014 | 0.024 |       |       | L        | 13.52       | 14.02 | 0.532  | 0.552 |       |
| c1       | 0.36   | 0.56   | 0.014 | 0.022 | 4     |       | L1       | 3.32        | 3.82  | 0.131  | 0.150 | 2     |
| D        | 14.85  | 15.25  | 0.585 | 0.600 | 3     |       | ØΡ       | 3.54        | 3.73  | 0.139  | 0.147 |       |
| D1       | 8.38   | 9.02   | 0.330 | 0.355 |       |       | Q        | 2.60        | 3.00  | 0.102  | 0.118 |       |

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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